



isc Silicon NPN Power Transistor

DESCRIPTION

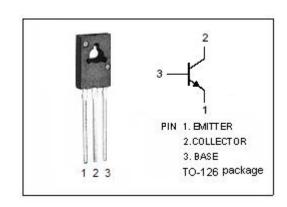
- · Collector-Emitter Breakdown Voltage
 - : V_{(BR)CEO}= 100V(Min)
- Good Linearity of hFE
- Complement to Type 2SA794
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

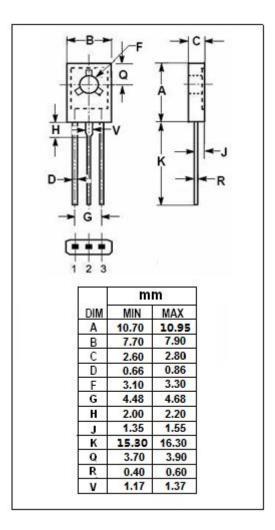
APPLICATIONS

- Designed for low-frequency high power driver.
- Optimum for the driver stage of low-frequency and 40W to 100W output amplifier.

ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT	
V _{CBO}	Collector-Base Voltage	100	V	
Vceo	Collector-Emitter Voltage	100	V	
V _{EBO}	Emitter-Base Voltage	5	V	
lc	Collector Current-Continuous	0.5	Α	
Іср	Collector Current-Peak	1	Α	
Pc	Collector Power Dissipation @ T _a =25 ℃	1.2	W	
TJ	T _J Junction Temperature		$^{\circ}$	
T _{stg}	T _{stg} Storage Temperature Range		$^{\circ}$	







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2SC1567

ELECTRICAL CHARACTERISTICS

T_C=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	I _C = 0.1mA ; I _B = 0	100			V
V _{(BR)EBO}	Emitter-Base Breakdown VItage	I _E = 1 μ A; I _C = 0	5			V
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = 500mA; I _B = 50mA			0.4	V
$V_{BE(sat)}$	Base-Emitter Saturation Voltage	I _C = 500mA; I _B = 50mA			1.2	V
h _{FE-1}	DC Current Gain	I _C = 150mA; V _{CE} = 10V	90		330	
h _{FE-2}	DC Current Gain	I _C = 500mA; V _{CE} = 5V	50			
fτ	Current-Gain—Bandwidth Product	I _E = -50mA ; V _{CB} = 10V		120		MHz
Сов	Output Capacitance	I _E = 0; V _{CB} = 10V,f _{test} = 1MHz		11		pF

♦ h_{FE1} Classifications

Q	R	S
90-155	130-220	185-330

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